Neodymium Doped Yttrium Orthovanadate (Nd:YVO_4)

Introduction

Nd:YVO_4 is the most efficient laser host crystal for diode pumping among the current commercial laser crystals, especially, for low to middle power density. This is mainly for its absorption and emission features surpassing Nd:YAG. Pumped by laser diodes, Nd:YVO_4 crystal has been incorporated with high NLO coefficient crystals (LBO, BBO, or KTP) to frequency-shift the output from the near infrared to green, blue, or even UV. This incorporation to construct all solid state lasers is an ideal laser tool that can cover the most widespread applications of lasers, including machining, material processing, spectroscopy, wafer inspection, light displays, medical diagnostics, laser printing, and data storage, etc. It has been shown that Nd:YVO_4 based diode pumped solid state lasers are rapidly occupying the markets traditionally dominated by water-cooled ion lasers and lamp-pumped lasers, especially when compact design and single-longitudinal-mode outputs are required.

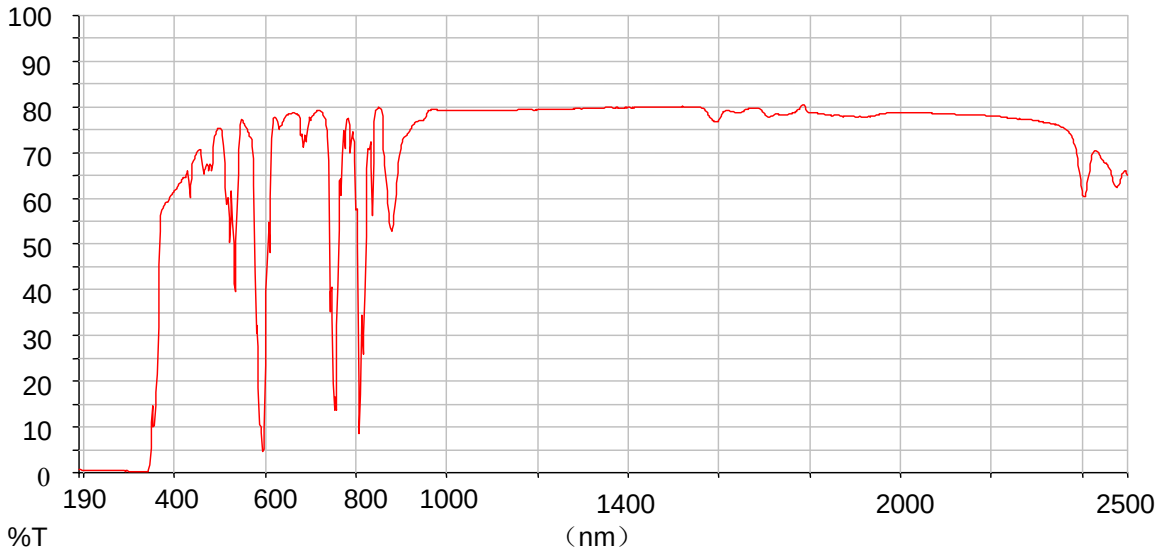
Nd:YVO_4 's advantages over Nd:YAG

- As high as about five times larger absorption efficient over a wide pumping bandwidth around 808 nm (therefore, the dependency on pumping wavelength is much lower and a strong tendency to the single mode output)
- As large as three times larger stimulated emission cross-section at the lasing wavelength of 1064nm
- Lower lasing threshold and higher slope efficiency
- As a uniaxial crystal with a large birefringence, the emission is only a linearly polarized.

CASTECH Provides

- Various doping concentration from 0.1% to 3%.
- Doping concentration tolerance:±0.05%(atm%<1%),±0.1%(atm%≥1%)
- Various size bulk and finished high quality Nd:YVO_4 crystals up to ϕ35x50mm^3 and ϕ20x20mm^3, respectively;
- 10,000 pcs of Nd:YVO_4 devices per month in sizes 3x3x0.5 to 4x4x8mm
- With quick delivery
- With competitive price.

Figure 1. Absorption Curve of 0.5% Nd:YVO_4(thickness 4mm)



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株式会社オプトサイエンス
http://www.optoscience.com
東 京 本 社 〒160-0014 東京都新宿区内藤町1番地 内藤町ビルディング TEL:03-3356-1064
大 阪 営 業 所 〒532-0011 大阪市淀川区西中島7-7-2 新大阪ビル西館 TEL:06-6305-2064
名古屋営業所 〒450-0002 名古屋市中村区名駅2-37-21 東海ソフトビル TEL:052-569-6064
E-mail : info@optoscience.com

Basic Properties

Crystal Structure: Cell Parameter:	Zircon Tetragonal, space group D_{4h}-I4/amd a=b=7.1193 Å, c=6.2892 Å
Density:	4.22g/cm^3
Atomic Density:	1.26x10^{20} atoms/cm^3 (Nd 1.0%)
Mohs Hardness:	4-5 (Glass-like)
Thermal Expansion Coefficient (300K):	α_a=4.43x10^{-6}/K α_c=11.37x10^{-6}/K
Thermal Conductivity Coefficient (300K):	//C: 0.0523W/cm/K ⊥C: 0.0510W/cm/K
Lasing wavelength:	1064nm, 1342nm
Thermal optical coefficient (300K):	dn_o/dT=8.5×10^{-6}/K dn_e/dT=2.9×10^{-6}/K
Stimulated emission cross-section:	25×10^{-19}cm^2 @1064nm
Fluorescent lifetime:	90μs (1% Nd doped)
Absorption coefficient:	31.4cm^{-1} @810nm
Intrinsic loss:	0.02cm^{-1} @1064nm
Gain bandwidth:	0.96nm @1064nm
Polarized laser emission:	π polarization; parallel to optical axis (c-axis)
Diode pumped optical to optical efficiency:	>60%
Sellmeier equations (λ in μm)	n_o^2=3.77834+0.069736/(λ ^{2}-0.04724)-0.010813 λ ^{2} n_e^2=4.59905 +0.110534/(λ ^{2}-0.04813)-0.012676 λ ^{2}

Laser Properties of Nd:YVO_4

1. One most attractive character of Nd:YVO_4 is, compared with Nd:YAG, its 5 times larger absorption coefficient in a broader absorption bandwidth around the 808nm peak pump wavelength, which just matches the standard of high power laser diodes currently available. This means a smaller crystal that could be used for the laser, leading to a more compact laser system. For a given output power, this also means a lower power level at which the laser diode operates, thus extending the lifetime of the expensive laser diode. The broader absorption bandwidth of Nd:YVO_4 which may reaches 2.4 to 6.3 times that of Nd:YAG. Besides more efficient pumping, it also means a broader range of selection of diode specifications. This will be helpful to laser system makers for wider tolerance for lower cost choice.

2. Nd:YVO_4 crystal has larger stimulated emission cross-sections, both at 1064nm and 1342nm. When a-axis cut Nd:YVO_4 crystal lasing at 1064m, it is about 4 times higher than that of Nd:YAG, while at 1340nm the stimulated cross-section is 18 times larger, which leads to a CW operation completely outperforming Nd:YAG at 1320nm. These make Nd:YVO_4 laser be easy to maintain a strong single line emission at the two wavelengths.

3. Another important character of Nd:YVO_4 lasers is, because it is an uniaxial rather than a high symmetry of cubic as Nd:YAG, it only emits a linearly polarized laser, thus avoiding undesired birefringent effects on the frequency conversion. Although the lifetime of Nd:YVO_4 is about 2.7 times shorter than that of Nd:YAG, its slope efficiency can be still quite high for a proper design of laser cavity, because of its high pump quantum efficiency.

The major laser properties of Nd:YVO_4 vs Nd:YAG are listed in Table below, including stimulated emission cross-sections (σ), absorption coefficient (α), fluorescent lifetime (τ), absorption length (L_α), threshold power (P_{th}) and pump quantum efficiency (η_s).

Laser Properties of Nd:YVO_4 vs Nd:YAG

LASER CRYSTAL	DOPING (atm%)	σ ($x10^{-19}cm^2$)	α (cm^{-1})	τ (μs)	L_α (mm)	P_{th} (mW)	η_S (%)
Nd:YVO_4(a-cut)	1.0 2.0	25 25	31.2 72.4	90 50	0.32 0.14	30 78	52 48.6
Nd:YVO_4(c-cut)	1.1	7	9.2	90		231	45.5
Nd:YAG	0.85	6	7.1	230	1.41	115	38.6

Typical Results

- **Diode pumped Nd:YVO_4 laser output comparing with diode pumped Nd:YAG laser.**

Crystals	Size (mm^3)	Pump Power	Output (at 1064nm)
Nd:YVO_4	3x3x1	850mW	350mW
Nd:YVO_4	3x3x5	15W	6W
Nd:YAG	3x3x2	850mW	34mW

- **Diode pumped Nd:YVO4+KTP green laser.**
- 8W green laser was generated from a 15W LD pumped 0.5%Nd:YVO_4 with intracavity KTP.
- 200mW green outputs are generated from 1 W LD pumped 2%Nd:YVO_4 lasers by using CASTECH's 2x2x5mm KTP and 3x3x1mm Nd:YVO_4.

CASTECH provides the following coatings

- Both ends AR/AR-1064/808nm, R<0.2%@1064nm,R<2%@808nm
- S1:HR@1064&532 nm,HT808 nm, R>99.8%@1064&532nm,T>90%@808nm
  S2:AR@1064&532 nm, R<0.2%@1064nm,R<0.5%@532nm
- S1:HR@1064,HT808, R>99.8%@1064nm,T>95%@808nm
  S2:AR@1064, R<0.1%@1064nm.
- S1,S2 AR-coated, S3:gold/chrome plated.
- Both ends AR/AR-1064 nm; S3:AR-808 nm
- Other coatings are available upon request.

CASTECH's Warranty on Nd:YVO_4 Specifications

- Dimension tolerance: (W±0.1mm)x(H±0.1mm)x(L+0.5/-0.1mm) (L≥2.5mm)
  (W±0.1mm)x(H±0.1mm)x(L+0.2/-0.1mm) (L<2.5mm)
- Clear aperture: central 90% of the diameter
- Flatness: less than λ/8 @ 633nm (L≥2.5mm); less than λ/4 @ 633nm (L<2.5mm)
- Transmitting wavefront distortion: less than λ/4 @ 633nm
- Chamfer: ≤0.2mm@45^0
- Chip: ≤0.1mm
- Scratch/Dig code: better than 10/ 5 to MIL-PRF-13830B
- Parallelism: better than 20 arc seconds
- Perpendicularity: ≤5 arc minutes
- Angle tolerance: ≤0.5°
- Damage threshold[GW/cm^2]: >1 for 1064nm, TEM00, 10ns, 10Hz (AR-coated)
- Quality Warranty Period: one year under proper use.